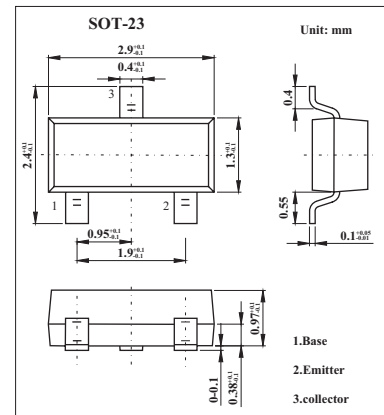


PNP General Purpose Transistors

BCX71H/J/K

■ Features

- Low current (max. 100 mA).
- Low voltage (max. 45 V).
- Low noise.

■ Absolute Maximum Ratings $T_a = 25^\circ\text{C}$

| Parameter | Symbol | Rating | Unit |
|---|---------------|-------------|------------------|
| Collector-base voltage | V_{CB0} | -45 | V |
| Collector-emitter voltage | V_{CE0} | -45 | V |
| Emitter-base voltage | V_{EB0} | -5 | V |
| Collector current | I_C | -100 | mA |
| Peak collector current | I_{CM} | -200 | mA |
| Peak base current | I_{BM} | -200 | mA |
| Total power dissipation | P_{tot} | 250 | mW |
| Storage temperature | T_{stg} | -65 to +150 | $^\circ\text{C}$ |
| Junction temperature | T_j | 150 | $^\circ\text{C}$ |
| Operating ambient temperature | R_{amb} | -65 to +150 | $^\circ\text{C}$ |
| Thermal resistance from junction to ambient * | $R_{th\ j-a}$ | 500 | K/W |

* Transistor mounted on an FR4 printed-circuit board.

BCX71H/J/K

■ Electrical Characteristics Ta = 25°C

| Parameter | Symbol | Testconditons | Min | Typ | Max | Unit |
|--------------------------------------|----------|--|------|------|-------|------|
| Collector cutoff current | ICBO | IE = 0; VCB = -45 V | | | -20 | nA |
| | ICBO | IE = 0; VCB = -45 V; Tamb = 150 °C | | | -20 | μA |
| Emitter cutoff current | IEBO | IC = 0; VEB = -4 V | | | -20 | nA |
| DC current gain | BCX71H | IC = -10 μA; VCE = -5 V | 30 | | | |
| | BCX71J | | 40 | | | |
| | BCX71K | | 100 | | | |
| DC current gain | BCX71H | IC = -2 mA; VCE = -5 V | 180 | | 310 | |
| | BCX71J | | 250 | | 460 | |
| | BCX71K | | 380 | | 630 | |
| DC current gain | BCX71H | IC = -50 mA; VCE = -1 V; * | 80 | | | |
| | BCX71J | | 100 | | | |
| | BCX71K | | 110 | | | |
| Collector-emitter saturation voltage | VCE(sat) | IC = -10 mA; IB = -0.25 mA | -60 | | -250 | mV |
| | | IC = -50 mA; IB = -1.25 mA; * | -120 | | -550 | mV |
| Base to emitter saturation voltage | VBE(sat) | IC = -10 mA; IB = -0.25 mA | -600 | | -850 | mV |
| | | IC = -50 mA; IB = -1.25 mA; * | -680 | | -1050 | mV |
| Base to emitter voltage | VBE | IC = -2 mA; VCE = -5 V | -600 | -650 | -750 | mV |
| Collector capacitance | CC | IE = IE = 0; VCB = -10 V; f = 1 MHz | | 4.5 | | pF |
| Emitter capacitance | Ce | IC = IC = 0; VEB = -0.5 V; f = 1 MHz | | 11 | | pF |
| Transition frequency | fT | IC = -10 mA; VCE = -5 V; f = 100 MHz | 100 | | | MHz |
| Noise figure | NF | IC = -200 μA; VCE = -5 V; Rs = 2 kΩ; f = 1 kHz; B = 200 Hz | | 2 | 6 | dB |

* Pulse test: tp ≤ 300 μs; d ≤ 0.02.

■ hFE Classification

| TYPE | BCX71H | BCX71J | BCX71K |
|---------|--------|--------|--------|
| Marking | BH | BJ | BK |